

## R-C Thermal Model Parameters

### DESCRIPTION

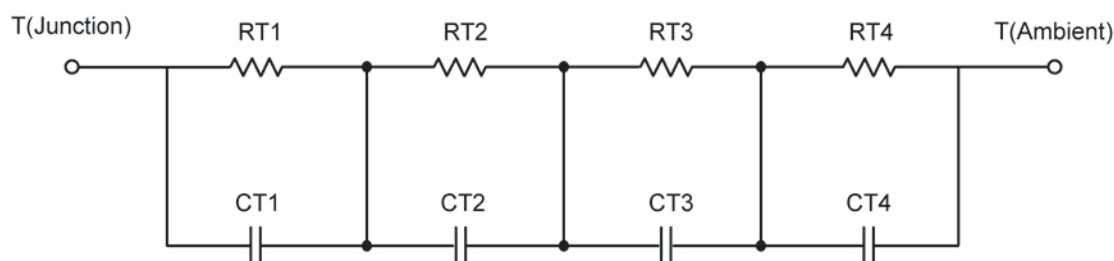
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

*Note:*

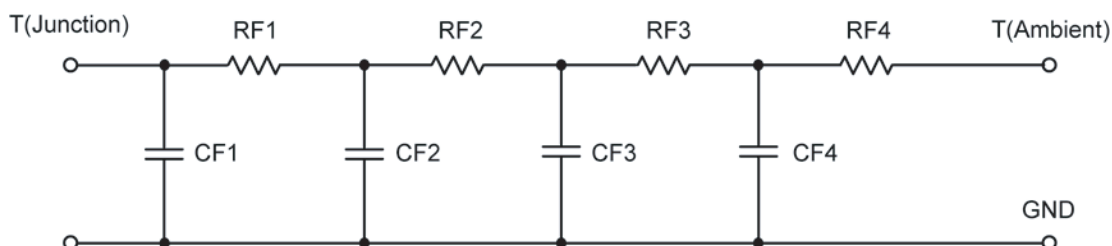
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	10.2157	N/A	24.5756
RT2	20.3157	N/A	7.1084
RT3	40.6039	N/A	10.5213
RT4	53.8647	N/A	12.7947
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	275.0620 u	N/A	1.1347 m
CT2	98.5796 m	N/A	130.9691 u
CT3	2.9226 m	N/A	91.5202 m
CT4	1.6678	N/A	5.1727 m

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	16.2372	N/A	11.5473
RF2	39.1284	N/A	21.9522
RF3	19.5756	N/A	12.0419
RF4	50.0588	N/A	9.4586
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	378.4797 u	N/A	137.8073 u
CF2	3.3087 m	N/A	1.0569 m
CF3	132.3272 m	N/A	93.1711 u
CF4	1.6838	N/A	103.0095 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

